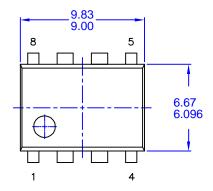
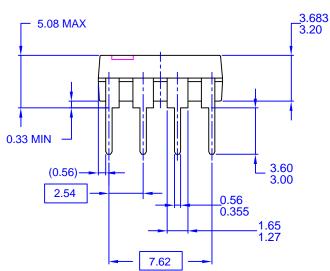
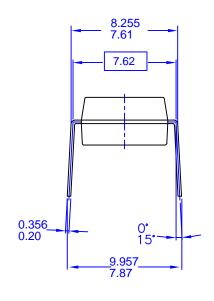
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REVISIONS									
LTR	DESCRIPTION	E.D.C.N.	DATE	BY/APP'D					
Α	RELEASE TO DOCUMENT CONTROL		05 APR2004	OS.JEON					
2	Dimension Composition	ECN-MKT-N08FR2	2 AUG 2007	H.ALLEN					







NOTES: UNLESS OTHERWISE SPECIFIED

- A) THIS PACKAGE CONFORMS TO JEDEC MS-001 VARIATION BA
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D) DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994
- E) DRAWING FILENAME AND REVSION: MKT-N08FREV2.

APPROVALS	DATE					
J. H MOON	22MAY2007	FAII	RC	HILE		
CHECKED: J. H MOON	22MAY2007	SEMICONDUCTOR+				
APPROVED: T. S KIM 22MAY2007		8LD, MDIP, JEDEC MS-001				
		.300" WIDE				
PROJECTION	7	3CALE 1:1	SIZE NA	DRAWING NUMBER MK	Γ-N08F	2 REV
INCH EMMO		FORMERLY:	N/A		SHEET : 1 (OF 1